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Design of Multilayer SIW Cavity-Backed Slot Antenna Array

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Abstract—In this paper, a multilayer substrate integrated waveguide (SIW) cavity-backed slot antenna array with wideband performance is proposed. In order to broaden the operating bandwidth of SIW slot antenna, multilayer cavities with gradually decreased permittivity and expanded aperture sizes are loaded above the slot, which realizes a smooth transition between SIW slot and free space. A wideband feeding network employing slot coupling is designed to excite the array elements. Results indicate the proposed array operates with 28.4% bandwidth ranging from 22.4 to 29.8 GHz. Besides, stable broadside radiation patterns are obtained across the operating band.

Index Terms—multilayer, array, substrate integrated waveguide, slot antenna.

## I. INTRODUCTION

In millimeter-wave band, substrate integrated waveguide (SIW) inherits merits from both microstrip lines and metal waveguides and exhibits advantages of easy fabrication, low transmission loss, and etc. Therefore, such electromagnetically closed planar waveguide structure has been employed as a good candidate for designing antenna arrays in millimeterwave band [1]. Cavity-backed slot antennas based on SIW have attracted many attentions and been proved to be useful in many applications.

As well known, SIW cavity-backed slot antenna has intrinsically narrow bandwidth. There have been several representative methods proposed in the past few years to enhance the bandwidth. Since the bandwidth of the cavity-backed slot antenna depended on the quality factor of the slot and cavity, the substrate under the slot was removed to broaden the bandwidth to 2.16% [2]. In [3], bandwidth of the SIW cavity-backed slot antenna could be enhanced to 6.3% by exciting hybrid SIW cavity modes. Through increasing the width to length ratio of the wide slot, dual resonances of SIW cavity-backed slot antenna were also generated and 11.6% bandwidth was achieved [4]. Besides, when the cavity-backed slot antenna was loaded with an open-ended cavity, the impedance bandwidth of a single element was enhanced to 23% [5].

As for designing cavity-backed slot antenna array, the feed network should be well builded to match the wideband performance of the array element. Despite of the excellent radiation performance, the bandwidths of series-feed and shunt-feed arrays were restricted since the radiators and feed network shared the same layer [6]-[8]. In our previous work, a novel

SIW cavity-backed slot antenna array without individual feed network was designed and 14% wide impedance bandwidth was obtained [9]. Based on the novel subarray, a large-scale corporate-feed antenna array with 15% bandwidth was presented [10]. Besides, an SIW higher order mode cavity-backed slot antenna array with simplified feed network was presented in [11]. The slots were arranged asymmetrically in the cavity to introduce new resonances and 16.7% bandwidth was obtained. When a larger bandwidth is further required, the state-of-art technologies fail to achieve breakthrough in broadening bandwidth due to the resonant characteristic of the slot element.

In this paper, a 16-element multilayer SIW cavity-backed slot antenna array is presented. The array element can be viewed as a modified open-ended cavity with variations both in aperture size and permittivity, which acts as a transition from the SIW cavity-backed slot to the air. The remainder of the paper is organized into three additional sections. In Section II, the feed network and a four-element subarray are specifically introduced. A 16-element array are presented and the simulated results are shown in Section III. Finally, the conclusion is drawn in Section IV.

### II. SUBARRAY DESIGN

Since array configuration shows much reliance on the feed network, a four-way power divider for feeding a subarray is specifically introduced, following by showing the performance of a four-element subarray. Based on the designing procedure, the array scale can be simply enlarged with increasing the scale of the feed network. The array is designed with the aid of High Frequency Structure Simulator (HFSS).

## A. 1-to-4 Power Divider

Fig. 1 depicts the configuration of the four-way power divider. The power divider consists of two layers with heights of  $h_1$  and  $h_2$ , respectively. The energy is input from port 1 in bottom layer and coupled through the slot with size of  $l_r \times w_r$  with spacings  $d_{x2}$  and  $d_{y2}$  to the endwall and sidewall, respectively. An adjusting via with spacings  $d_{x1}$  and  $d_{y1}$  to the endwall and sidewall is adopted to further realize good coupling effect. When the energy arrives at the top layer of the feed network, a coupling window with size of  $l_g \times w_g$  is opened to distribute the energy equally in four ways. An adjusting via

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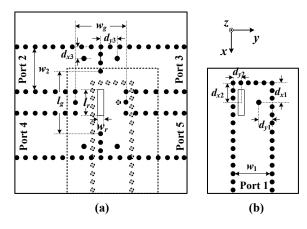


Fig. 1. Configuration of the 1-to-4 power divider. (a) Perspective view of the power divider. (b) Top view of the bottom layer.

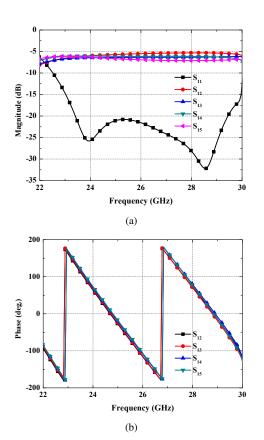


Fig. 2. Simulated results of the 1-to-4 power divider. (a) S-parameters. (b) Phases.

is placed with spacings  $d_{x3}$  and  $d_{y3}$  to the corner to realize good transition from the coupling window to the sub-channels.

The results of the power divider are calculated in Fig. 2 with the parameters listed in Table I. In the simulated band ranging from 22.5 to 30 GHz, the reflection coefficients are below -10 dB. Moreover, within this simulated band, the magnitude difference is less than 2.5 dB while phase error of the four outputs is less than 12 degrees.

 $\label{eq:table_interpolation} TABLE\ I$  Parameters of the power divider. (Unit: mm).

Symbol	Quantity	Symbol	Quantity
$d_{x1}$	3	$w_1$	6.5
$d_{y1}$	2.2	$w_2$	7
$d_{x2}$	1.3	$w_g$	8
$d_{y2}$	3	$l_g$	10
$d_{x3}$	1.6	$w_r$	1.2
$d_{y3}$	2.5	$l_r$	5.5
$h_1$	0.5	$h_2$	1

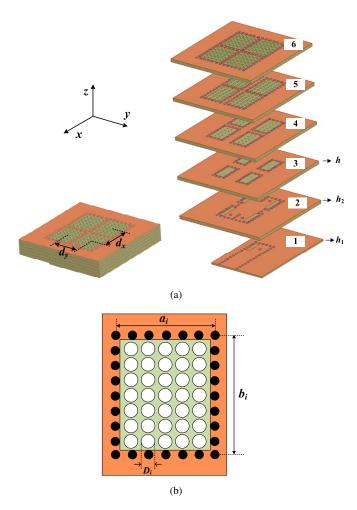


Fig. 3. Configuration of the four-element subarray. (a) Whole and anatomy views. (c) Cavity cell.

#### B. Design of Four-Element Subarray

Since the outputs of the four-way power divider are almost in-phase, array elements can be placed symmetrically with related to the centre of the power divider. The geometrical configuration of the four elements subarray is depicted in Fig. 3. This subarray is made by six layers and the feed network occupies the bottom two layers. In order to excite the horn elements, the four-way power divider is shorted by metallized vias to form a cavity and four slots are placed at the corners of the cavity to convert the vertically polarized wave in the power

TABLE II
PARAMETERS OF THE SUBARRAY. (UNIT: MM).

Symbol	Quantity	Symbol	Quantity
$a_1$	3.1	$D_1$	0
$b_1$	6.5	$D_2$	0.4
$a_2$	4.7	$D_3$	0.9
$b_2$	8.1	$D_4$	1.2
$a_3$	6.3	$d_x$	10.3
$b_3$	9.7	$d_y$	9.2
$a_4$	7.9	h	1
$b_4$	9.7	d	1.6

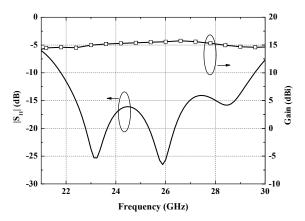


Fig. 4. Simulated reflection coefficients and broadside gains of the fourelement array.

divider into the horizontally polarized wave in the multilayer cavities. The cavities, made by four PCB boards with a same height h, are directly placed above the slots. The aperture size of a cavity cell in the ith layer is  $a_i \times b_i$  and air vias with diameter of  $D_i$  are perforated in the cavity to manipulate the permittivity. The cavity walls are made by the surrounded metallized vias with diameter of d. The element spacings in x- and y-direction are defined as  $d_x$  and  $d_y$ .

A four-element subarray is designed and simulated with the parameters listed in Table II. As shown in Fig. 4, this subarray owns 30.6% impedance bandwidth in the frequency range from 21.8 GHz to 29.7 GHz with  $|S_{11}|$  below -10 dB. In this band, a flat gain response fluctuant around 15 dBi is obtained. Besides, stable broadside radiation patterns can be observed in Fig. 5. By the way, when the operating frequency goes high to 29.7 GHz, a relatively high side lobe level is resulted, which mainly comes from the increased element spacings in comparison with the operating wavelength.

## III. ARRAY DESIGN AND RESULTS

The four-element subarray can be easily extended to a 16-element array when an H-shaped power divider is employed, as shown in Fig. 6. A prototype is fabricated and the photograph is shown in Fig. 7. A transition from microstrip line to SIW is designed and a connecting device is employed to facilitate the measurement of antenna performance. All the prototypes

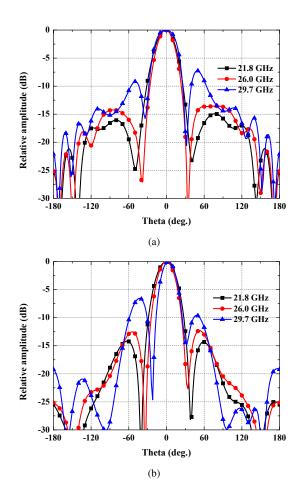


Fig. 5. Simulated radiation patterns of the four-element array at three representing frequencies. (a) E-plane. (b) H-plane.

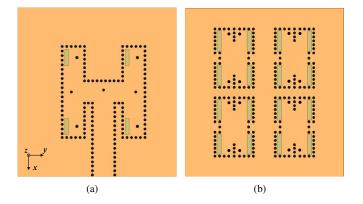


Fig. 6. Configuration of the feed network for the proposed array. (a) Layer 1. (b) Layer 2.

are fabricated using Rogers RT/Duroid 5880 PCB boards with permittivity of 2.2 and loss tangent of 0.0009.

The simulated reflection coefficients and broadside gains are calculated in Fig. 8. It can be observed that in the band ranging from 22.4 to 29.8 GHz, the simulated  $|S_{11}|$ s are below -10 dB and the relative impedance bandwidth of the designed array reaches to 28.4%. Besides, the simulated broadside gains are also calculated in this figure. A flat gain response fluctuant around 20 dBi with up to 2 dBi gain variation is obtained. The far-field radiation patterns at three representing frequencies

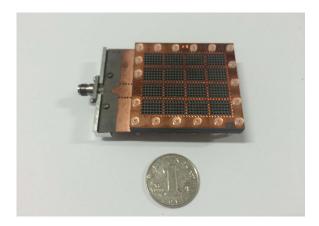


Fig. 7. Photograph of the fabricated prototype.

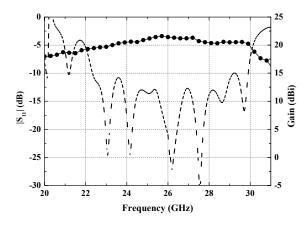


Fig. 8. Simulated reflection coefficients and gains of the proposed array.

in the operating band are plotted in Fig. 9. The simulated side lobe level is typically below -10 dB, and stable broadside radiation pattern is obtained within the operating band.

# IV. CONCLUSION

In the paper, a multilayer SIW horn antenna array with wideband performance is proposed. Through loading multilayer horn cavities with both gradually increased aperture sizes and decreased permittivity, a smooth transition is realized between the SIW cavity-backed slot antenna and the free space. Moreover, considering the extensibility of the array, a dual-layer corporate-feed network based on slot-coupling is employed for feeding the array elements. Results indicate the proposed antenna array achieves up to 28.4% operating bandwidth with stable broadside radiation patterns across the whole operating band.

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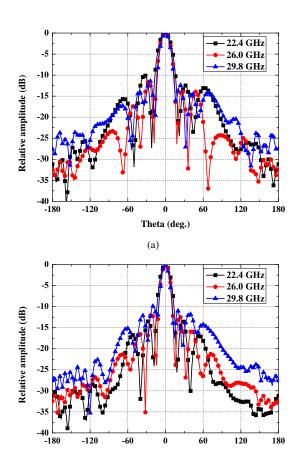


Fig. 9. Simulated radiation patterns of the proposed array at three representing frequencies. (a) E-plane. (b) H-plane.

(b)

Theta (deg.)

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